NSN 5961-01-190-7776

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
3.00 amperes forward current, average absolute
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0